

## Quad channel high side driver for automotive applications

### Features

|                                   |           |                          |
|-----------------------------------|-----------|--------------------------|
| Max transient supply voltage      | $V_{CC}$  | 41V                      |
| Operating voltage range           | $V_{CC}$  | 4.5 to 36 V              |
| Max on-state resistance (per ch.) | $R_{ON}$  | 160 m $\Omega$           |
| Current limitation (typ)          | $I_{LMH}$ | 5.4 A                    |
| Off-state supply current          | $I_S$     | 2 $\mu$ A <sup>(1)</sup> |

1. Typical value with all loads connected

#### ■ General features

- Inrush current active management by power limitation
- Very low standby current
- 3.0 V CMOS compatible input
- Optimized electromagnetic emission
- Very low electromagnetic susceptibility
- In compliance with the 2002/95/EC European directive

#### ■ Diagnostic functions

- Open drain status output
- On-state open-load detection
- Off-state open-load detection
- Thermal shutdown indication

#### ■ Protection

- Undervoltage shutdown
- Overvoltage clamp
- Output stuck to  $V_{CC}$  detection
- Load current limitation
- Self limiting of fast thermal transients
- Protection against loss of ground and loss of  $V_{CC}$
- Thermal shut down
- Reverse battery protection (see [Application schematic on page 18](#))



- Electrostatic discharge protection

### Applications

- All types of resistive, inductive and capacitive loads

### Description

The VNQ5160K-E is a monolithic device made using STMicroelectronics VIPower™ M0-5 technology. It is intended for driving resistive or inductive loads with one side connected to ground. Active  $V_{CC}$  pin voltage clamp protects the device against low energy spikes (see ISO7637 transient compatibility table).

The device detects open-load condition in both on and off states, when STAT\_DIS is left open or driven low. Output shorted to  $V_{CC}$  is detected in the off-state. When STAT\_DIS is driven high, the STATUS pin is in a high impedance condition.

Output current limitation protects the device in overload condition. In the case of long duration overload, the device limits the dissipated power to a safe level up to thermal shutdown intervention.

Thermal shutdown with automatic restart allows the device to recover normal operation as soon as a fault condition disappears.

**Table 1. Device summary**

| Package     | Order codes |               |
|-------------|-------------|---------------|
|             | Tube        | Tape and reel |
| PowerSSO-24 | VNQ5160K-E  | VNQ5160KTR-E  |

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# 1 Block diagram and pin configuration

Figure 1. Block diagram

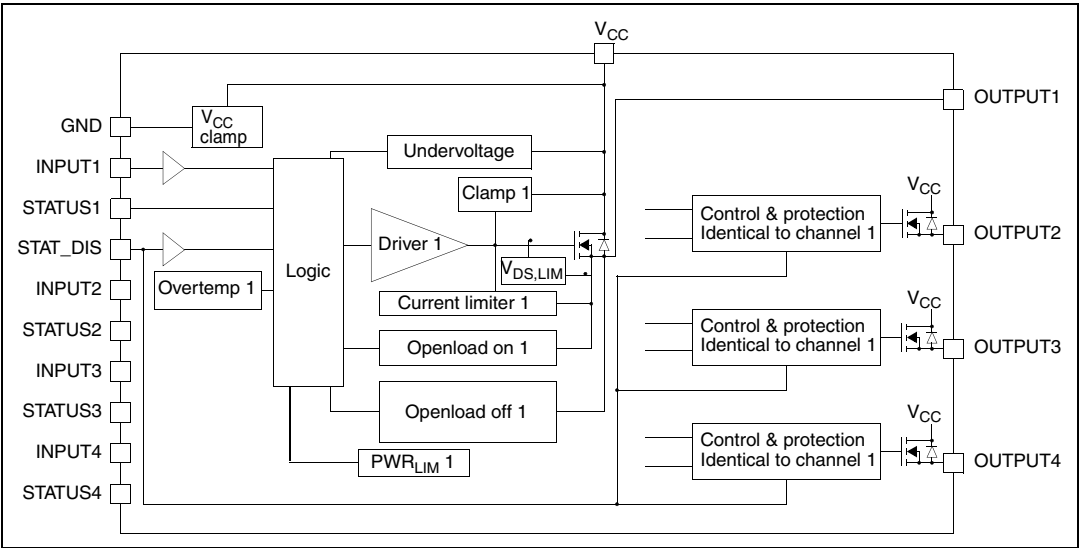


Table 2. Pin functions

| Name            | Function                                                                                    |
|-----------------|---------------------------------------------------------------------------------------------|
| V <sub>CC</sub> | Battery connection                                                                          |
| OUTPUTn         | Power output                                                                                |
| GND             | Ground connection. Must be reverse battery protected by an external diode/resistor network  |
| INPUTn          | Voltage controlled input pin with hysteresis, CMOS compatible. Controls output switch state |
| STATUSn         | Open drain digital diagnostic pin                                                           |
| STAT_DIS        | Active high CMOS compatible pin, to disable the STATUS pin                                  |

Figure 2. Configuration diagram (top view)

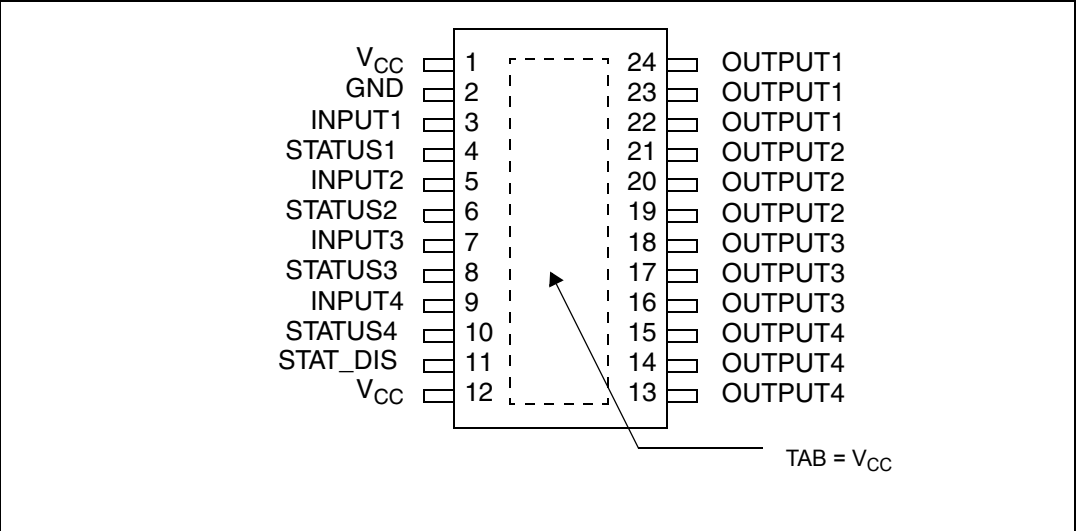


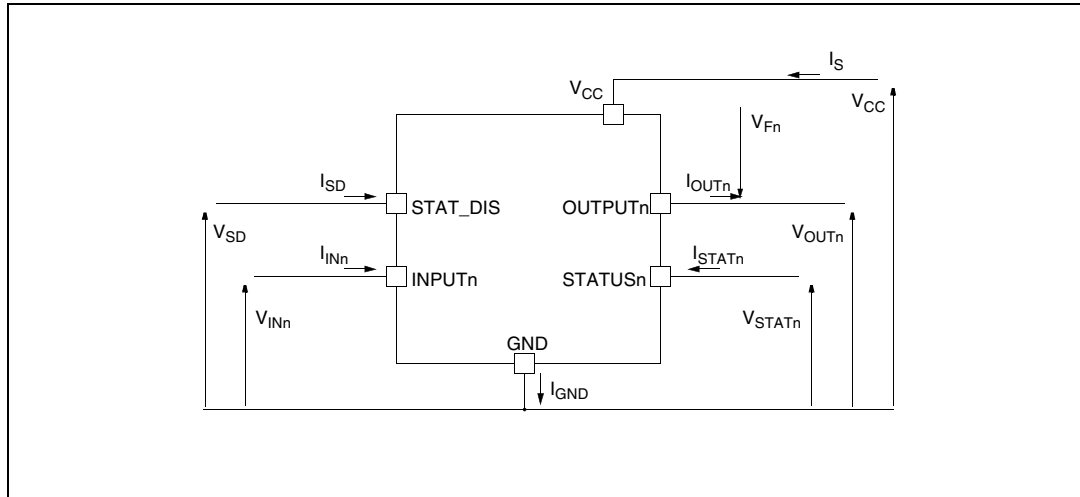
Table 3. Suggested connections for unused and not connected pins

| Connection / Pin | Status              | N.C. | Output | Input                  | STAT_DIS               |
|------------------|---------------------|------|--------|------------------------|------------------------|
| Floating         | X                   | X    | X      | X                      | X                      |
| To ground        | N.R. <sup>(1)</sup> | X    | N.R.   | Through 10 kΩ resistor | Through 10 kΩ resistor |

1. Not recommended

## 2 Electrical specifications

Figure 3. Current and voltage conventions



Note:  $V_{Fn} = V_{OUTn} - V_{CCn}$  during reverse battery condition

### 2.1 Absolute maximum ratings

Table 4. Absolute maximum ratings

| Symbol          | Parameter                                                                                                                                                                    | Value              | Unit |
|-----------------|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|--------------------|------|
| $V_{CC}$        | DC supply voltage                                                                                                                                                            | 41                 | V    |
| $-V_{CC}$       | Reverse DC supply voltage                                                                                                                                                    | 0.3                | V    |
| $-I_{GND}$      | DC reverse ground pin current                                                                                                                                                | 200                | mA   |
| $I_{OUT}$       | DC output current                                                                                                                                                            | Internally limited | A    |
| $-I_{OUT}$      | Reverse DC output current                                                                                                                                                    | 6                  | A    |
| $I_{IN}$        | DC input current                                                                                                                                                             | +10 / -1           | mA   |
| $I_{STAT}$      | DC status current                                                                                                                                                            | +10 / -1           | mA   |
| $I_{STAT\_DIS}$ | DC status disable current                                                                                                                                                    | +10 / -1           | mA   |
| $E_{MAX}$       | Maximum switching energy (single pulse)<br>( $L=12\text{mH}$ ; $R_L=0\Omega$ ; $V_{bat}=13.5\text{V}$ ; $T_{jstart}=150^\circ\text{C}$ ; $I_{OUT} = I_{limL}(\text{Typ.})$ ) | 33                 | mJ   |
| $V_{ESD}$       | Electrostatic discharge (Human Body Model: $R=1.5\text{K}\Omega$ ; $C=100\text{pF}$ )                                                                                        |                    |      |
|                 | – Input                                                                                                                                                                      | 4000               | V    |
|                 | – Status                                                                                                                                                                     | 4000               | V    |
|                 | – STAT_DIS                                                                                                                                                                   | 4000               | V    |
|                 | – Output                                                                                                                                                                     | 5000               | V    |
|                 | – $V_{CC}$                                                                                                                                                                   | 5000               | V    |
| $V_{ESD}$       | Charge device model (CDM-AEC-Q100-011)                                                                                                                                       | 750                | V    |

**Table 4. Absolute maximum ratings (continued)**

| Symbol    | Parameter                      | Value       | Unit |
|-----------|--------------------------------|-------------|------|
| $T_j$     | Junction operating temperature | -40 to 150  | °C   |
| $T_{stg}$ | Storage temperature            | - 55 to 150 | °C   |

## 2.2 Thermal data

**Table 5. Thermal data**

| Symbol         | Parameter                                                 | Max. value                      | Unit |
|----------------|-----------------------------------------------------------|---------------------------------|------|
| $R_{thj-case}$ | Thermal resistance junction-case<br>(with one channel on) | 8                               | °C/W |
| $R_{thj-amb}$  | Thermal resistance junction-ambient                       | See <a href="#">Figure 32</a> . | °C/W |

## 2.3 Electrical characteristics

8V <  $V_{CC}$  < 36V; -40°C <  $T_j$  < 150°C, unless otherwise specified

**Table 6. Power section**

| Symbol        | Parameter                                      | Test conditions                                                                                                               | Min.   | Typ.                  | Max.                   | Unit           |
|---------------|------------------------------------------------|-------------------------------------------------------------------------------------------------------------------------------|--------|-----------------------|------------------------|----------------|
| $V_{CC}$      | Operating supply voltage                       |                                                                                                                               | 4.5    | 13                    | 36                     | V              |
| $V_{USD}$     | Undervoltage shutdown                          |                                                                                                                               |        | 3.5                   | 4.5                    | V              |
| $V_{USDhyst}$ | Undervoltage shutdown hysteresis               |                                                                                                                               |        | 0.5                   |                        | V              |
| $R_{ON}$      | On-state resistance <sup>(1)</sup>             | $I_{OUT}=1A$ ; $T_j=25^\circ C$<br>$I_{OUT}=1A$ ; $T_j=150^\circ C$<br>$I_{OUT}=1A$ ; $V_{CC}=5V$ ; $T_j=25^\circ C$          |        |                       | 160<br>320<br>210      | mΩ<br>mΩ<br>mΩ |
| $V_{clamp}$   | Clamp voltage                                  | $I_S=20\text{ mA}$                                                                                                            | 41     | 46                    | 52                     | V              |
| $I_S$         | Supply current                                 | Off-state; $V_{CC}=13V$ ; $V_{IN}=V_{OUT}=0V$ ;<br>$T_j=25^\circ C$<br>On-state; $V_{IN}=5V$ ; $V_{CC}=13V$ ;<br>$I_{OUT}=0A$ |        | 2 <sup>(2)</sup><br>8 | 5 <sup>(2)</sup><br>14 | μA<br>mA       |
| $I_{L(off1)}$ | Off-state output current <sup>(1)</sup>        | $V_{IN}=V_{OUT}=0V$ ; $V_{CC}=13V$ ; $T_j=25^\circ C$<br>$V_{IN}=V_{OUT}=0V$ ; $V_{CC}=13V$ ; $T_j=125^\circ C$               | 0<br>0 | 0.01                  | 3<br>5                 | μA<br>μA       |
| $I_{L(off2)}$ | Off-state output current <sup>(1)</sup>        | $V_{IN}=0V$ ; $V_{OUT}=4V$                                                                                                    | -75    |                       | 0                      | μA             |
| $V_F$         | Output - $V_{CC}$ diode voltage <sup>(1)</sup> | $-I_{OUT}=0.6A$ ; $T_j=150^\circ C$                                                                                           |        |                       | 0.7                    | V              |

1. For each channel.

2. PowerMOS leakage included.

**Table 7. Switching ( $V_{CC} = 13V$ ;  $T_j = 25^\circ C$ )**

| Symbol                | Parameter                                 | Test conditions                                   | Min. | Typ.                          | Max. | Unit      |
|-----------------------|-------------------------------------------|---------------------------------------------------|------|-------------------------------|------|-----------|
| $t_{d(on)}$           | Turn-on delay time                        | $R_L = 13\Omega$ (see <a href="#">Figure 6.</a> ) |      | 15                            |      | $\mu s$   |
| $t_{d(off)}$          | Turn-off delay time                       | $R_L = 13\Omega$ (see <a href="#">Figure 6.</a> ) |      | 15                            |      | $\mu s$   |
| $dV_{OUT}/dt_{(on)}$  | Turn-on voltage slope                     | $R_L = 13\Omega$                                  |      | See <a href="#">Figure 6.</a> |      | $V/\mu s$ |
| $dV_{OUT}/dt_{(off)}$ | Turn-off voltage slope                    | $R_L = 13\Omega$                                  |      | See <a href="#">Figure 6.</a> |      | $V/\mu s$ |
| $W_{ON}$              | Switching energy losses during $t_{won}$  | $R_L = 13\Omega$ (see <a href="#">Figure 6.</a> ) |      | 0.05                          |      | mJ        |
| $W_{OFF}$             | Switching energy losses during $t_{woff}$ | $R_L = 13\Omega$ (see <a href="#">Figure 6.</a> ) |      | 0.03                          |      | mJ        |

**Table 8. Status pin ( $V_{SD}=0$ )**

| Symbol      | Parameter                    | Test conditions                                       | Min | Typ  | Max | Unit    |
|-------------|------------------------------|-------------------------------------------------------|-----|------|-----|---------|
| $V_{STAT}$  | Status low output voltage    | $I_{STAT} = 1.6\text{ mA}$ , $V_{SD}=0V$              |     |      | 0.5 | V       |
| $I_{LSTAT}$ | Status leakage current       | Normal operation or $V_{SD}=5V$ , $V_{STAT}=5V$       |     |      | 10  | $\mu A$ |
| $C_{STAT}$  | Status pin input capacitance | Normal operation or $V_{SD}=5V$ , $V_{STAT}=5V$       |     |      | 100 | pF      |
| $V_{SCL}$   | Status clamp voltage         | $I_{STAT} = 1\text{ mA}$<br>$I_{STAT} = -1\text{ mA}$ | 5.5 | -0.7 | 7   | V<br>V  |

**Table 9. Protection<sup>(1)</sup>**

| Symbol     | Parameter                                    | Test conditions                                  | Min.         | Typ.         | Max.       | Unit       |
|------------|----------------------------------------------|--------------------------------------------------|--------------|--------------|------------|------------|
| $I_{limH}$ | DC Short circuit current                     | $V_{CC}=13V$<br>$5V < V_{CC} < 36V$              | 3.8          | 5.4          | 7.5<br>7.5 | A<br>A     |
| $I_{limL}$ | Short circuit current during thermal cycling | $V_{CC}=13V$<br>$T_R < T_j < T_{TSD}$            |              | 2            |            | A          |
| $T_{TSD}$  | Shutdown temperature                         |                                                  | 150          | 175          | 200        | $^\circ C$ |
| $T_R$      | Reset temperature                            |                                                  | $T_{RS} + 1$ | $T_{RS} + 5$ |            | $^\circ C$ |
| $T_{RS}$   | Thermal reset of STATUS                      |                                                  | 135          |              |            | $^\circ C$ |
| $T_{HYST}$ | Thermal hysteresis ( $T_{TSD}-T_R$ )         |                                                  |              | 7            |            | $^\circ C$ |
| $t_{SDL}$  | Status delay in overload conditions          | $T_j > T_{TSD}$ (See <a href="#">Figure 4.</a> ) |              |              | 20         | $\mu s$    |

**Table 9. Protection<sup>(1)</sup> (continued)**

| Symbol             | Parameter                      | Test conditions                                                                                                                   | Min.               | Typ.               | Max.               | Unit |
|--------------------|--------------------------------|-----------------------------------------------------------------------------------------------------------------------------------|--------------------|--------------------|--------------------|------|
| $V_{\text{DEMAG}}$ | Turn-off output voltage clamp  | $I_{\text{OUT}}=1\text{A}$ ; $V_{\text{IN}}=0$ ; $L=20\text{mH}$                                                                  | $V_{\text{CC}}-41$ | $V_{\text{CC}}-46$ | $V_{\text{CC}}-52$ | V    |
| $V_{\text{ON}}$    | Output voltage drop limitation | $I_{\text{OUT}}=0.03\text{A}$ (see <a href="#">Figure 5.</a> )<br>$T_{\text{J}} = -40^{\circ}\text{C} \dots +150^{\circ}\text{C}$ |                    | 25                 |                    | mV   |

1. To ensure long term reliability under heavy overload or short circuit conditions, protection and related diagnostic signals must be used together with a proper software strategy. If the device is subjected to abnormal conditions, this software must limit the duration and number of activation cycles

**Table 10. Open-load detection**

| Symbol               | Parameter                                                                      | Test conditions                                                                               | Min | Typ                            | Max              | Unit          |
|----------------------|--------------------------------------------------------------------------------|-----------------------------------------------------------------------------------------------|-----|--------------------------------|------------------|---------------|
| $I_{\text{OL}}$      | Open-load on-state detection threshold                                         | $V_{\text{IN}} = 5\text{V}$ , $8\text{V} < V_{\text{CC}} < 18\text{V}$                        | 10  | See <a href="#">Figure 18.</a> | 40               | mA            |
| $t_{\text{DOL(on)}}$ | Open-load on-state detection delay                                             | $I_{\text{OUT}} = 0\text{A}$ , $V_{\text{CC}}=13\text{V}$<br>(See <a href="#">Figure 4.</a> ) |     |                                | 200              | $\mu\text{s}$ |
| $t_{\text{POL}}$     | Delay between INPUT falling edge and STATUS rising edge in Open-load condition | $I_{\text{OUT}} = 0\text{A}$ (See <a href="#">Figure 4.</a> )                                 | 200 | 500                            | 1000             | $\mu\text{s}$ |
| $V_{\text{OL}}$      | Open-load OFF-state voltage detection threshold                                | $V_{\text{IN}} = 0\text{V}$ , $8\text{V} < V_{\text{CC}} < 16\text{V}$                        | 2   | See <a href="#">Figure 19.</a> | 4                | V             |
| $t_{\text{DSTKON}}$  | Output short circuit to $V_{\text{CC}}$ detection delay at turn-off            | (See <a href="#">Figure 4.</a> )                                                              | 180 |                                | $t_{\text{POL}}$ | $\mu\text{s}$ |

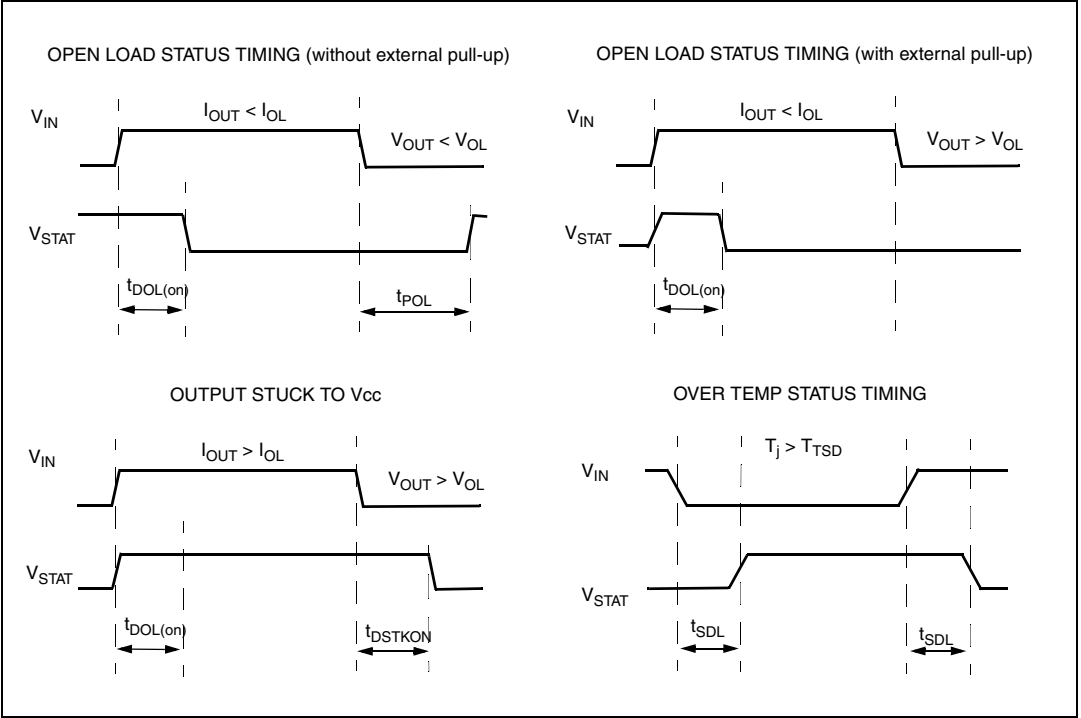
**Table 11. Logic input**

| Symbol               | Parameter                   | Test conditions                                               | Min. | Typ. | Max. | Unit          |
|----------------------|-----------------------------|---------------------------------------------------------------|------|------|------|---------------|
| $V_{\text{IL}}$      | Input low level             |                                                               |      |      | 0.9  | V             |
| $I_{\text{IL}}$      | Low level input current     | $V_{\text{IN}} = 0.9\text{V}$                                 | 1    |      |      | $\mu\text{A}$ |
| $V_{\text{IH}}$      | Input high level            |                                                               | 2.1  |      |      | V             |
| $I_{\text{IH}}$      | High level input current    | $V_{\text{IN}} = 2.1\text{V}$                                 |      |      | 10   | $\mu\text{A}$ |
| $V_{\text{I(hyst)}}$ | Input hysteresis voltage    |                                                               | 0.25 |      |      | V             |
| $V_{\text{ICL}}$     | Input clamp voltage         | $I_{\text{IN}} = 1\text{mA}$<br>$I_{\text{IN}} = -1\text{mA}$ | 5.5  | -0.7 | 7    | V<br>V        |
| $V_{\text{SDL}}$     | STAT_DIS low level voltage  |                                                               |      |      | 0.9  | V             |
| $I_{\text{SDL}}$     | Low level STAT_DIS current  | $V_{\text{SD}}=0.9\text{V}$                                   | 1    |      |      | $\mu\text{A}$ |
| $V_{\text{SDH}}$     | STAT_DIS high level voltage |                                                               | 2.1  |      |      | V             |

**Table 11. Logic input (continued)**

| Symbol         | Parameter                   | Test conditions               | Min. | Typ. | Max. | Unit    |
|----------------|-----------------------------|-------------------------------|------|------|------|---------|
| $I_{SDH}$      | High level STAT_DIS current | $V_{SD}=2.1V$                 |      |      | 10   | $\mu A$ |
| $V_{SD(hyst)}$ | STAT_DIS hysteresis voltage |                               | 0.25 |      |      | V       |
| $V_{SDCL}$     | STAT_DIS clamp voltage      | $I_{SD}=1mA$<br>$I_{SD}=-1mA$ | 5.5  | -0.7 | 7    | V<br>V  |

**Figure 4. Status timings**



**Figure 5. Output voltage drop limitation**

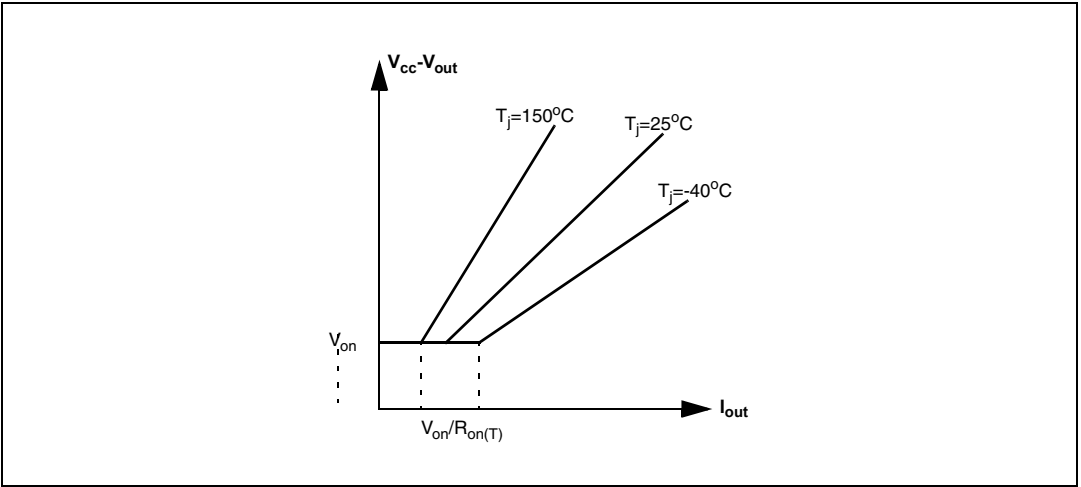
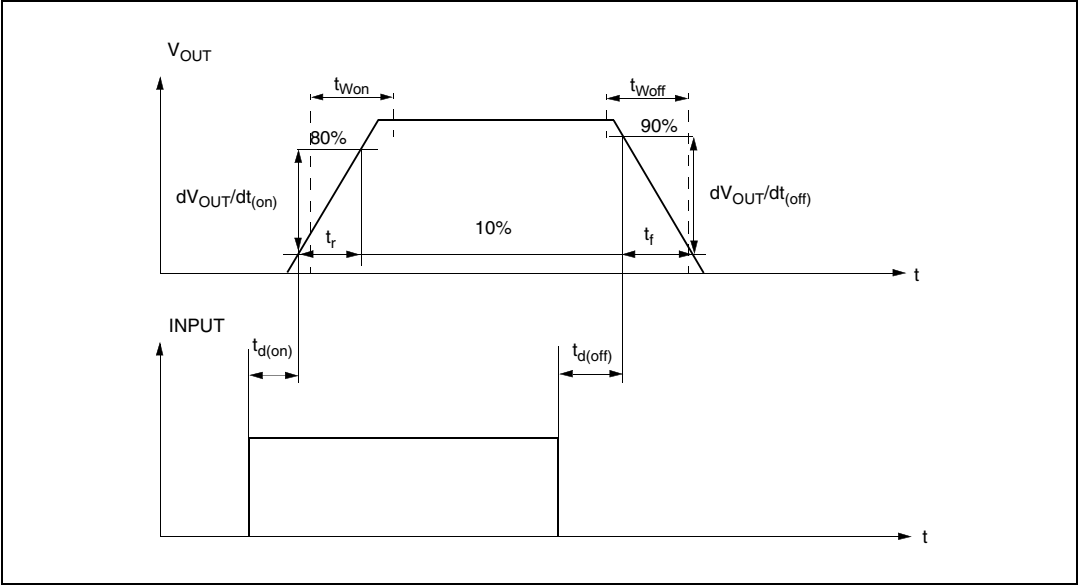


Table 12. Truth table

| Conditions                | INPUTn | OUTPUTn | STATUSn ( $V_{SD}=0V$ ) <sup>(1)</sup> |
|---------------------------|--------|---------|----------------------------------------|
| Normal operation          | L      | L       | H                                      |
|                           | H      | H       | H                                      |
| Current limitation        | L      | L       | H                                      |
|                           | H      | X       | H                                      |
| Overtemperature           | L      | L       | H                                      |
|                           | H      | L       | L                                      |
| Undervoltage              | L      | L       | X                                      |
|                           | H      | L       | X                                      |
| Output voltage > $V_{OL}$ | L      | H       | L <sup>(2)</sup>                       |
|                           | H      | H       | H                                      |
| Output current < $I_{OL}$ | L      | L       | H <sup>(3)</sup>                       |
|                           | H      | H       | L                                      |

- 1. If the  $V_{SD}$  is high, the STATUS pin is in a high impedance.
- 2. The STATUS pin is low with a delay equal to  $t_{DSTKON}$  after INPUT falling edge.
- 3. The STATUS pin becomes high with a delay equal to  $t_{POL}$  after INPUT falling edge.

Figure 6. Switching characteristics



**Table 13. Electrical transient requirements (part 1/3)**

| ISO 7637-2:<br>2004(E)<br>Test pulse | Test levels <sup>(1)</sup> |        | Number of<br>pulses or<br>test times | Burst cycle/pulse<br>repetition time |        | Delays and<br>Impedance  |
|--------------------------------------|----------------------------|--------|--------------------------------------|--------------------------------------|--------|--------------------------|
|                                      | III                        | IV     |                                      |                                      |        |                          |
| 1                                    | -75 V                      | -100 V | 5000<br>pulses                       | 0.5 s                                | 5 s    | 2 ms, 10 $\Omega$        |
| 2a                                   | +37 V                      | +50 V  | 5000<br>pulses                       | 0.2 s                                | 5 s    | 50 $\mu$ s, 2 $\Omega$   |
| 3a                                   | -100 V                     | -150 V | 1h                                   | 90 ms                                | 100 ms | 0.1 $\mu$ s, 50 $\Omega$ |
| 3b                                   | +75 V                      | +100 V | 1h                                   | 90 ms                                | 100 ms | 0.1 $\mu$ s, 50 $\Omega$ |
| 4                                    | -6 V                       | -7 V   | 1 pulse                              |                                      |        | 100 ms, 0.01 $\Omega$    |
| 5b <sup>(1)</sup>                    | +65 V                      | +87 V  | 1 pulse                              |                                      |        | 400 ms, 2 $\Omega$       |

1. Valid in case of external load dump clamp: 40V maximum referred to ground.

**Table 14. Electrical transient requirements (part 2/3)**

| ISO 7637-2:<br>2004(E)<br>Test pulse | Test level results <sup>(1)</sup> |    |
|--------------------------------------|-----------------------------------|----|
|                                      | III                               | IV |
| 1                                    | C                                 | C  |
| 2a                                   | C                                 | C  |
| 3a                                   | C                                 | C  |
| 3b                                   | C                                 | C  |
| 4                                    | C                                 | C  |
| 5b <sup>(2)</sup>                    | C                                 | C  |

1. The above test levels must be considered referred to Vcc = 13.5V except for pulse 5b

2. Valid in case of external load dump clamp: 40V maximum referred to ground.

**Table 15. Electrical transient requirements (part 3/3)**

| Class | Contents                                                                                                                                                                 |
|-------|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| C     | All functions of the device are performed as designed after exposure to disturbance.                                                                                     |
| E     | One or more functions of the device are not performed as designed after exposure to disturbance and cannot be returned to proper operation without replacing the device. |

2.4 Electrical characteristics curves

Figure 7. Off-state output current

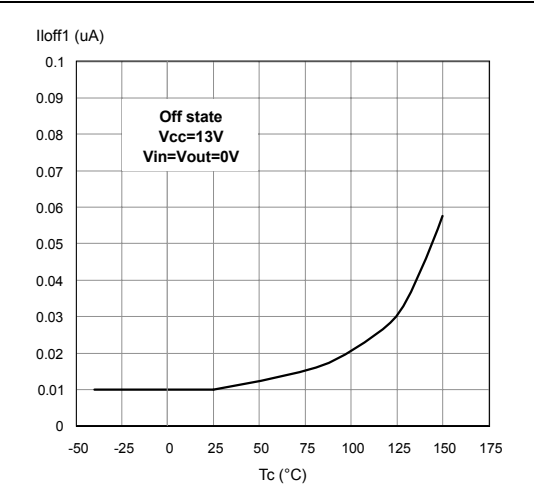


Figure 8. High level input current

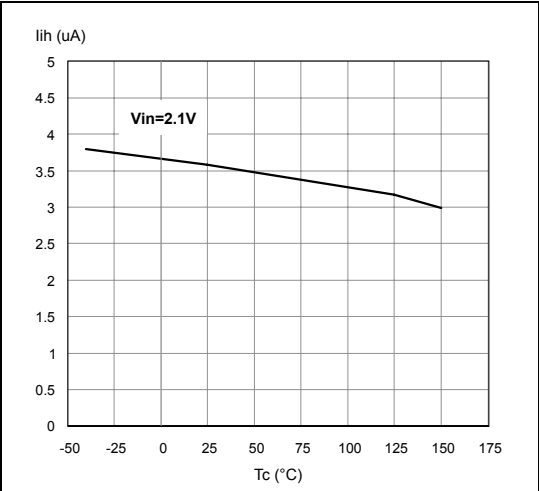


Figure 9. Input clamp voltage

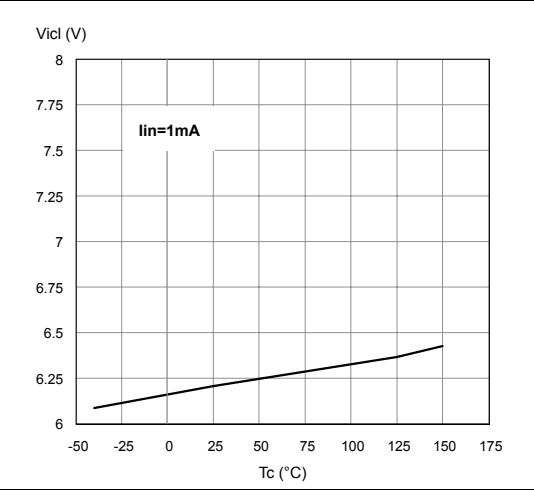


Figure 10. Input low level voltage

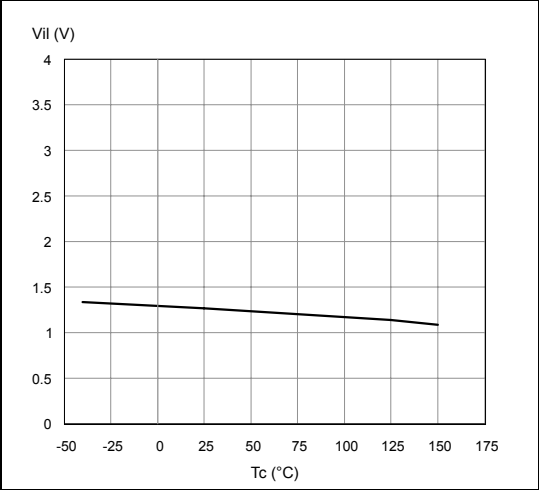


Figure 11. Input high level voltage

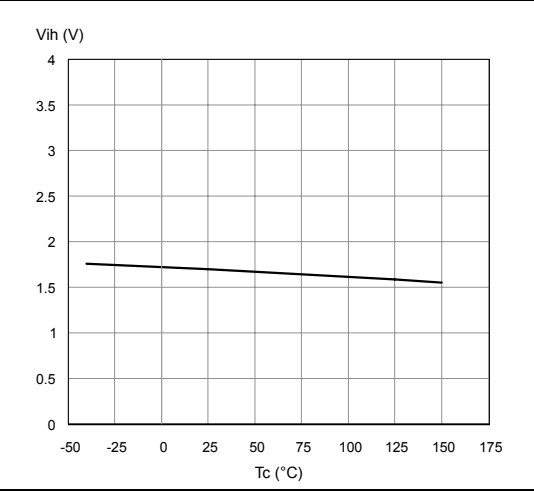


Figure 12. Input hysteresis voltage

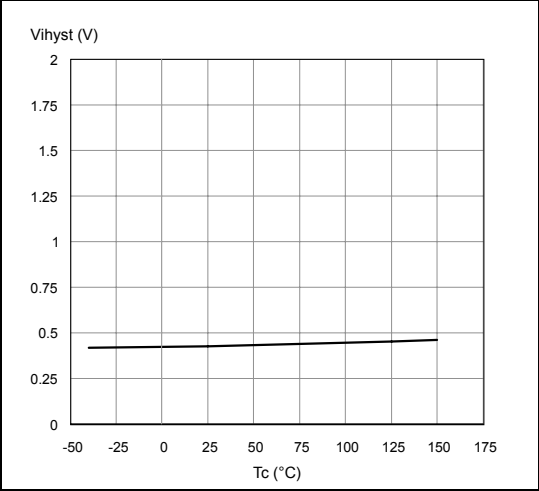


Figure 13. Status low output voltage

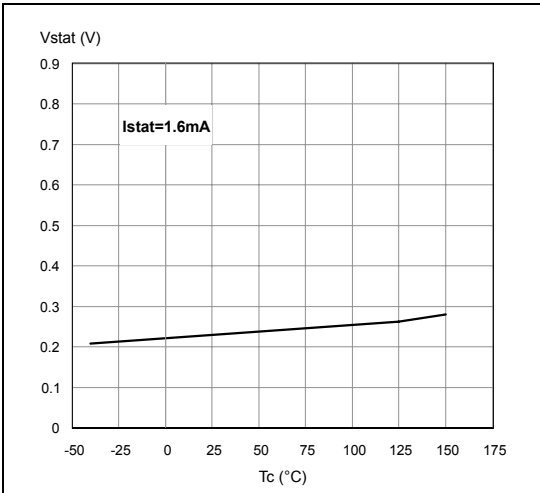


Figure 14. Status leakage current

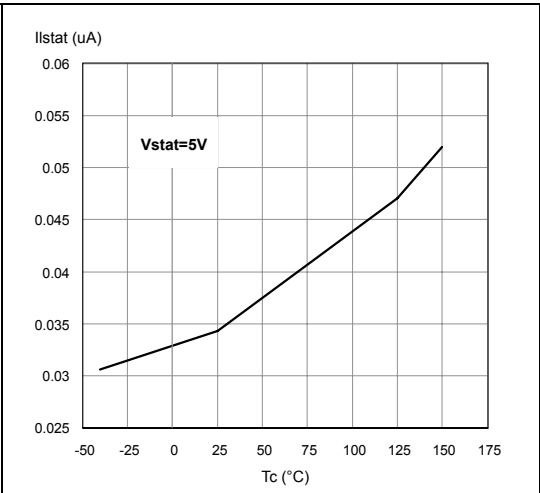


Figure 15. On-state resistance vs  $T_{case}$

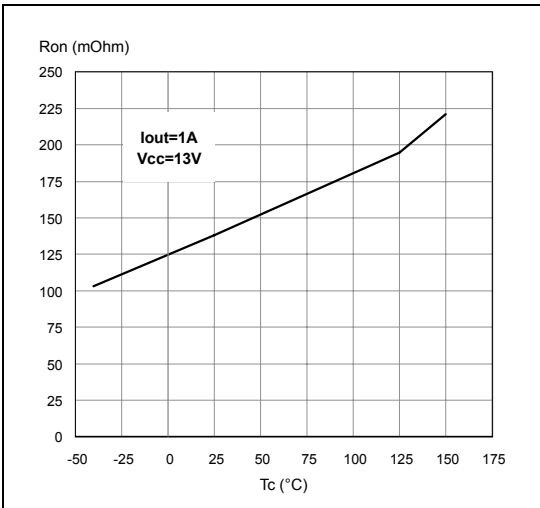


Figure 16. On-state resistance vs  $V_{CC}$

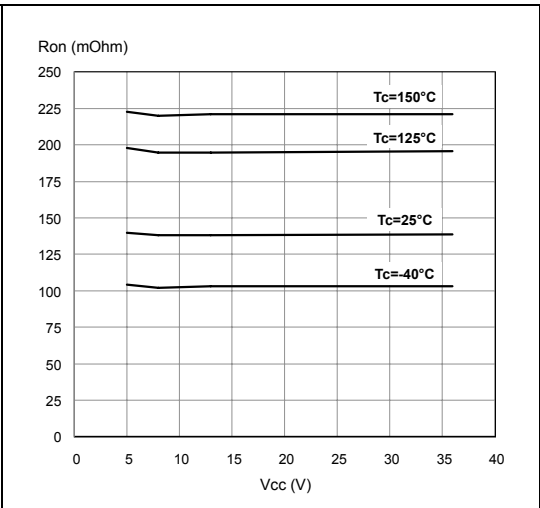


Figure 17. Status clamp voltage

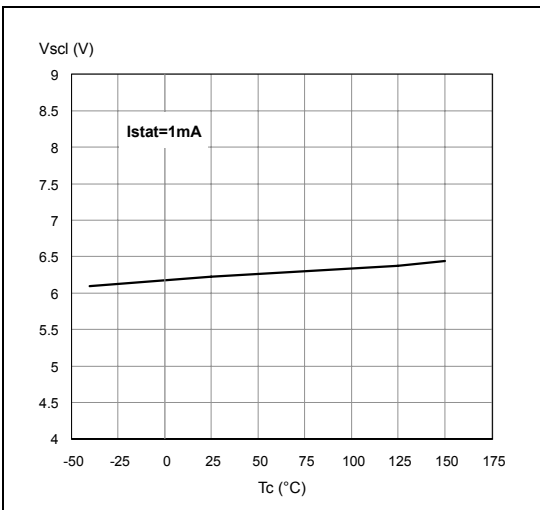


Figure 18. Open-load on-state detection threshold

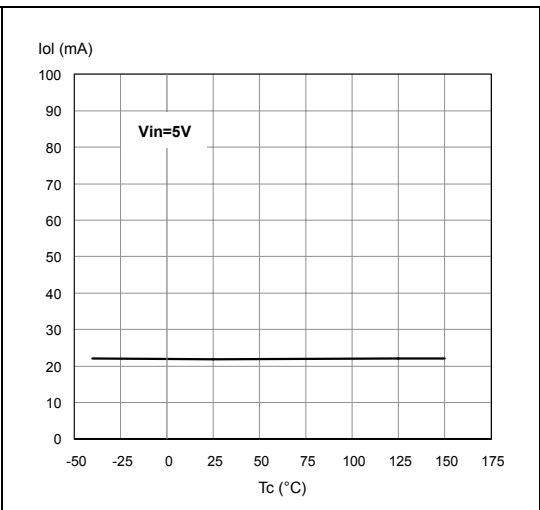


Figure 19. Open-load off-state voltage detection threshold

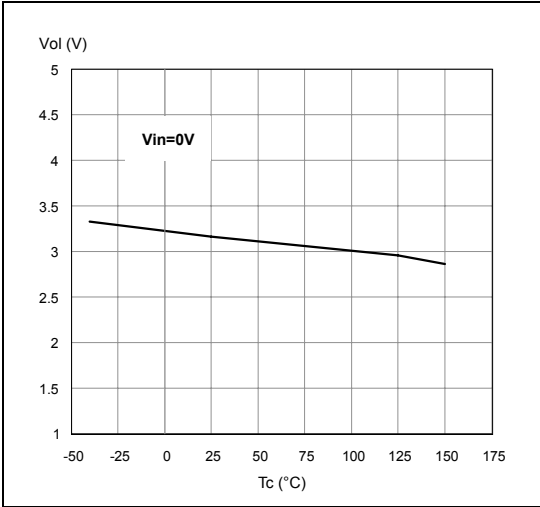


Figure 20. Undervoltage shutdown

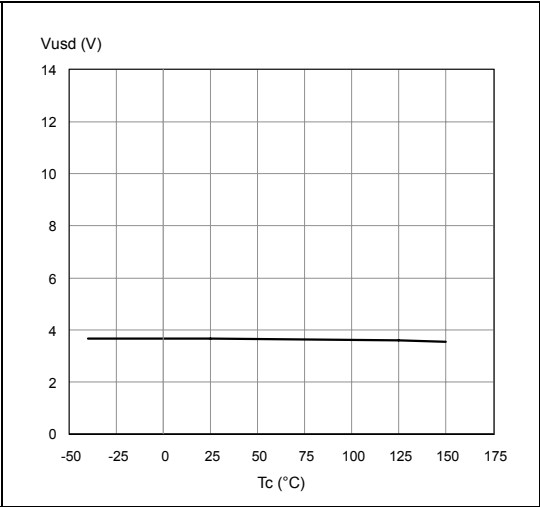


Figure 21. Turn-on voltage slope

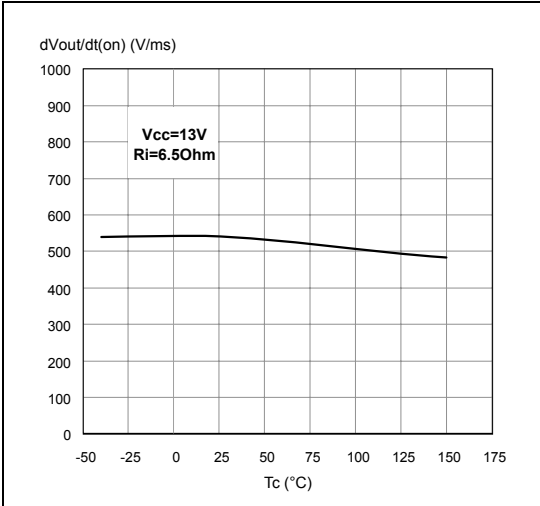


Figure 22. I<sub>LIMH</sub> vs T<sub>case</sub>

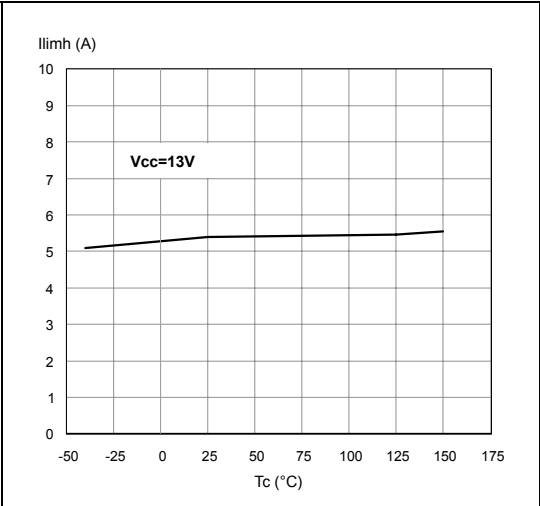


Figure 23. Turn-off voltage slope

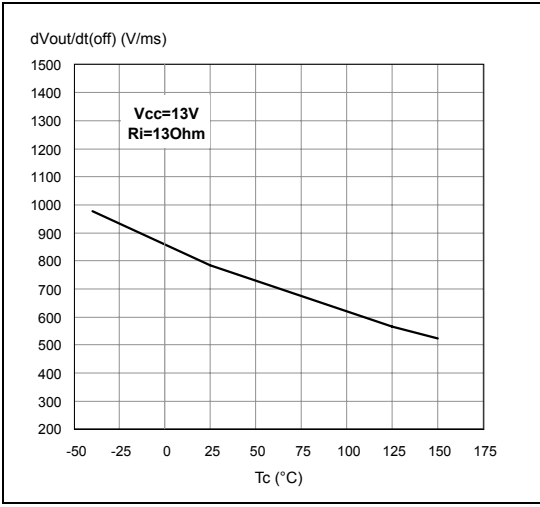


Figure 24. High-level STAT\_DIS voltage

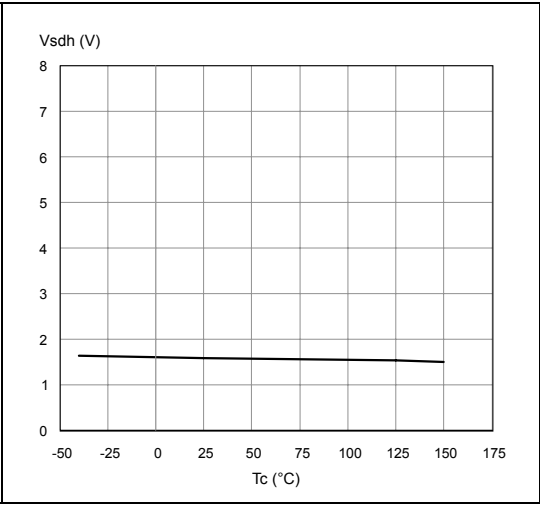


Figure 25. STAT\_DIS clamp voltage

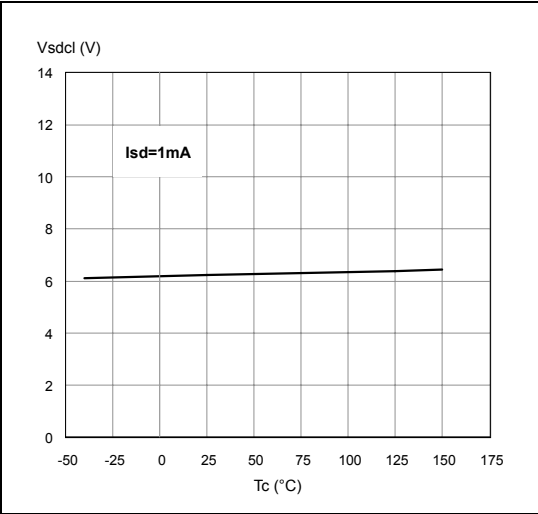
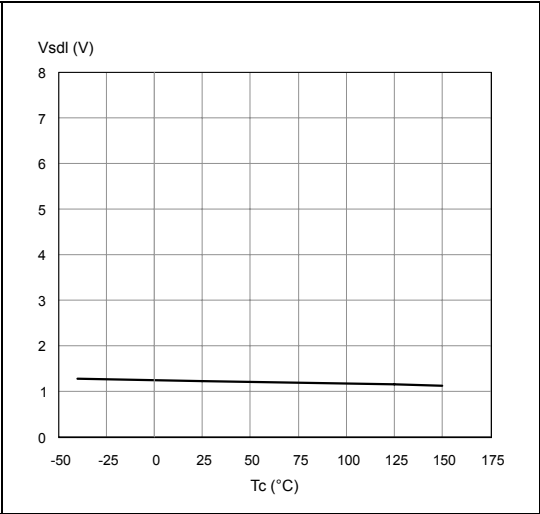
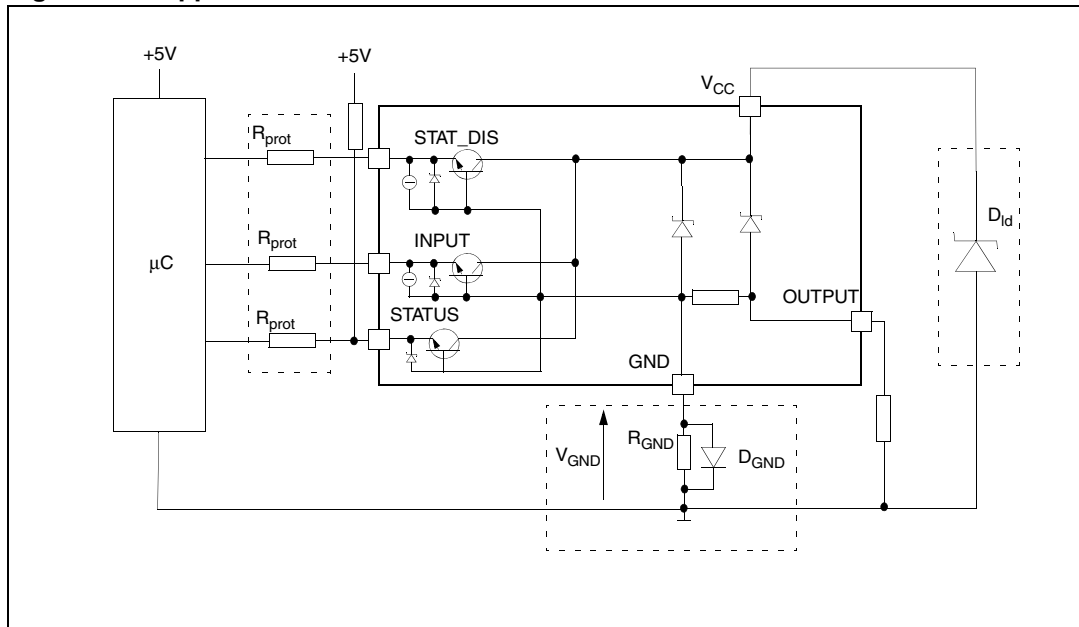


Figure 26. Low level STAT\_DIS voltage



### 3 Application information

Figure 27. Application schematic



Note: Channels 2, 3 and 4 have the same internal circuit as channel 1.

## 3.1 GND protection network against reverse battery

### 3.1.1 Solution 1: resistor in the ground line ( $R_{GND}$ only).

This solution can be used with any type of load.

The following is an indication on how to dimension the  $R_{GND}$  resistor.

1.  $R_{GND} \leq 600\text{mV} / (I_{S(on)max})$ .
2.  $R_{GND} \geq (-V_{CC}) / (-I_{GND})$

where  $-I_{GND}$  is the DC reverse ground pin current and can be found in the absolute maximum rating section of the device datasheet.

Power dissipation in  $R_{GND}$  (when  $V_{CC} < 0$ : during reverse battery situations) is:

$$P_D = (-V_{CC})^2 / R_{GND}$$

This resistor can be shared amongst several different HSDs. Please note that the value of this resistor should be calculated with formula (1) where  $I_{S(on)max}$  becomes the sum of the maximum on-state currents of the different devices.

Please note that if the microprocessor ground is not shared by the device ground then the  $R_{GND}$  will produce a shift ( $I_{S(on)max} * R_{GND}$ ) in the input thresholds and the status output values. This shift will vary depending on how many devices are ON in the case of several high side drivers sharing the same  $R_{GND}$ .

If the calculated power dissipation leads to a large resistor or several devices have to share the same resistor then ST suggests that Solution 2 is used (see below).

### 3.1.2 Solution 2: a diode ( $D_{GND}$ ) in the ground line.

A resistor ( $R_{GND}=1k\Omega$ ) should be inserted in parallel with  $D_{GND}$  if the device drives an inductive load.

This small signal diode can be safely shared amongst several different HSDs. Also in this case, the presence of the ground network will produce a shift ( $\sim 600mV$ ) in the input threshold and in the status output values if the microprocessor ground is not common with the device ground. This shift will not vary if more than one HSD shares the same diode/resistor network.

## 3.2 Load dump protection

$D_{ld}$  is necessary (Voltage Transient Suppressor) if the load dump peak voltage exceeds to  $V_{CC}$  max DC rating. The same applies if the device is subject to transients on the  $V_{CC}$  line that are greater than the ones shown in the ISO T/R 7637/1 table.

## 3.3 Microcontroller I/Os protection

If a ground protection network is used and negative transients are present on the  $V_{CC}$  line, the control pins will be pulled negative. ST suggests the insertion of resistors ( $R_{prot}$ ) in the lines to prevent the  $\mu C$  I/Os pins from latching up.

The values of these resistors are a compromise between the leakage current of  $\mu C$  and the current required by the HSD I/Os (input levels compatibility) with the latch-up limit of the  $\mu C$  I/Os.

$$-V_{CCpeak}/I_{latchup} \leq R_{prot} \leq (V_{OH\mu C} - V_{IH} - V_{GND}) / I_{IHmax}$$

Calculation example:

For  $V_{CCpeak} = -100V$  and  $I_{latchup} \geq 20mA$ ;  $V_{OH\mu C} \geq 4.5V$

$$5k\Omega \leq R_{prot} \leq 65k\Omega$$

Recommended  $R_{prot}$  value is  $10k\Omega$ .

## 3.4 Open-load detection in off-state

Off-state open-load detection requires an external pull-up resistor ( $R_{PU}$ ) connected between the OUTPUT pin and a positive supply voltage ( $V_{PU}$ ) like the +5V line used to supply the microprocessor.

The external resistor has to be selected according to the following requirements:

1. No false open-load indication when load is connected: in this case we have to avoid  $V_{OUT}$  to be higher than  $V_{OLmin}$ ; this results in the following condition:  

$$V_{OUT} = (V_{PU} / (R_L + R_{PU})) R_L < V_{OLmin}.$$
2. No misdetection when the load is disconnected: in this case the  $V_{OUT}$  has to be higher than  $V_{OLmax}$ ; this results in the following condition:  

$$R_{PU} < (V_{PU} - V_{OLmax}) / I_{L(off2)}.$$

Because  $I_{S(OFF)}$  may significantly increase if  $V_{out}$  is pulled high (up to several mA), the pull-up resistor  $R_{PU}$  should be connected to a supply that is switched OFF when the module is in standby.

The values of  $V_{OLmin}$ ,  $V_{OLmax}$  and  $I_{L(off2)}$  are available in the Electrical characteristics section.

**Figure 28. Open-load detection in off-state**

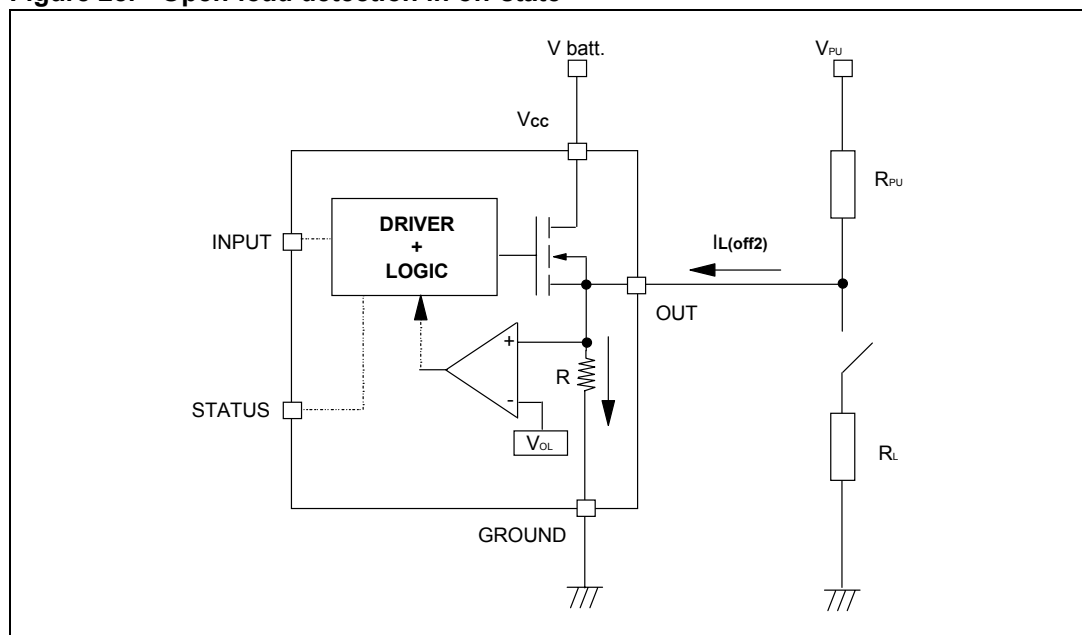
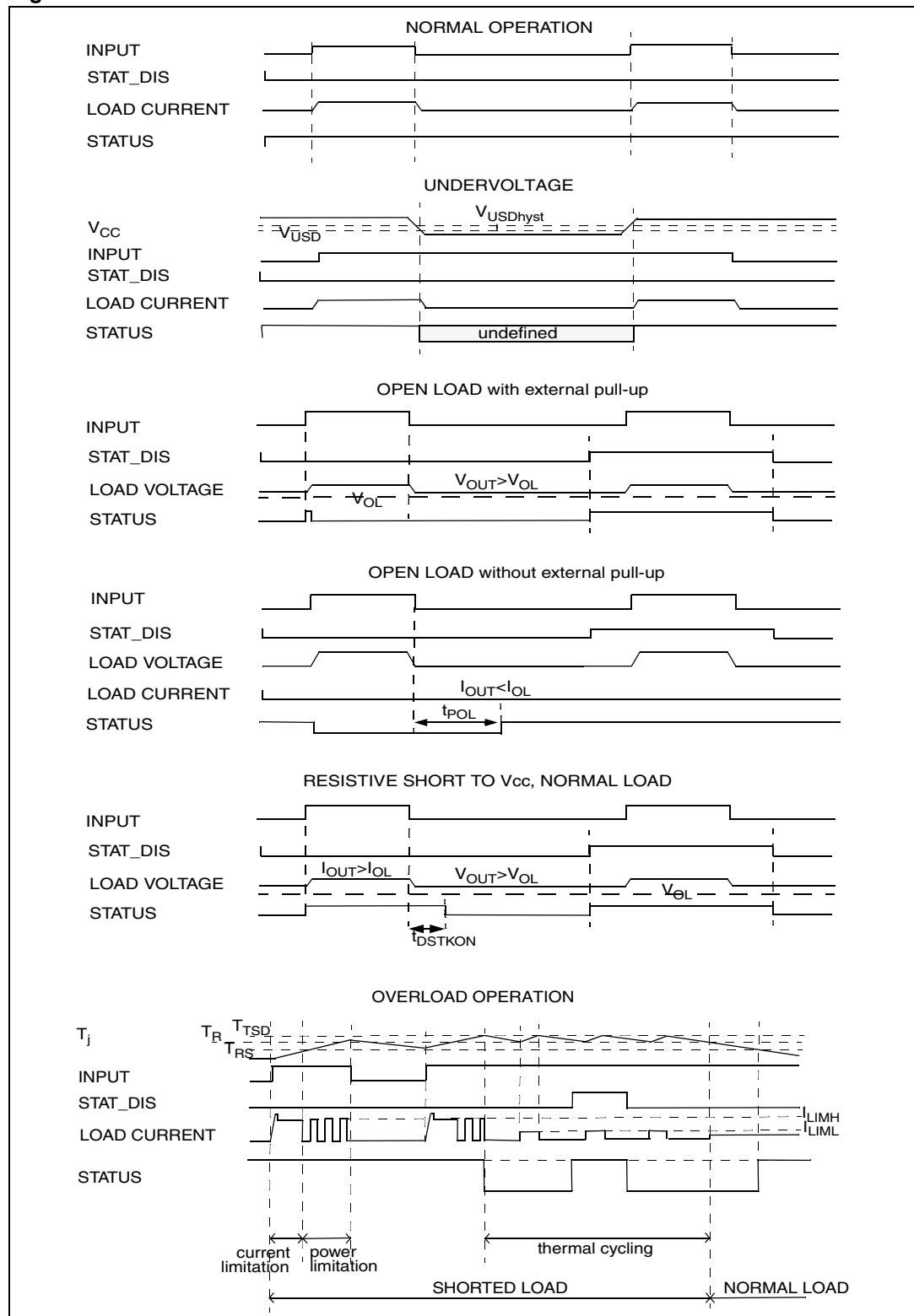
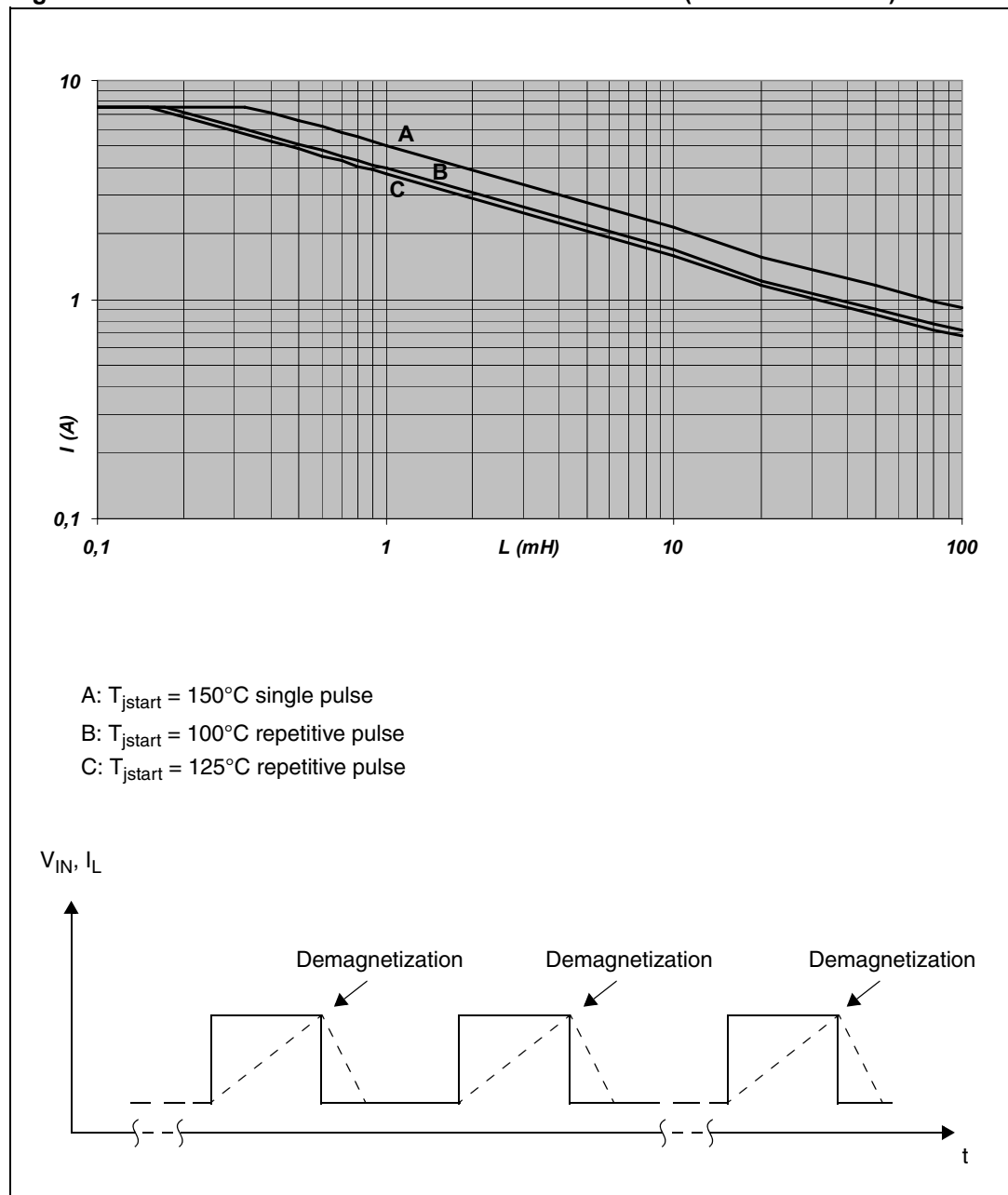


Figure 29. Waveforms



### 3.5 Maximum demagnetization energy ( $V_{CC} = 13.5V$ )

Figure 30. Maximum turn-off current versus inductance (for each channel)



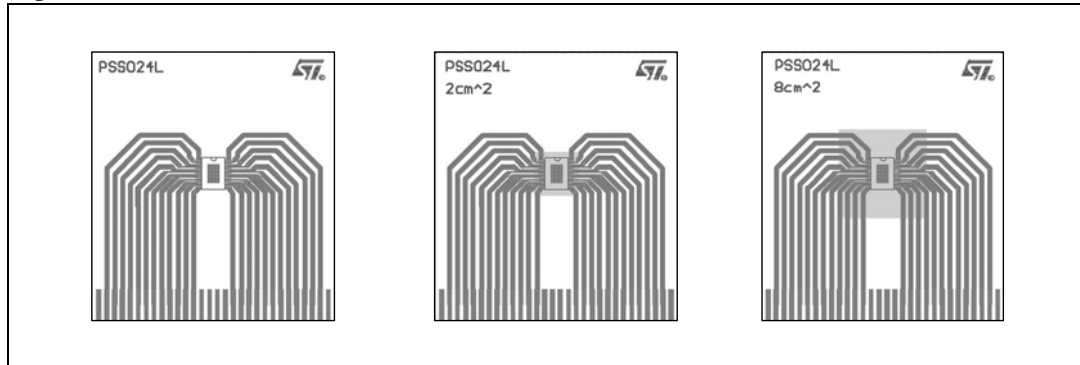
Note: Values are generated with  $R_L = 0\Omega$

In case of repetitive pulses,  $T_{jstart}$  (at beginning of each demagnetization) of every pulse must not exceed the temperature specified above for curves A and B.

## 4 Package and PC board thermal data

### 4.1 PowerSSO-24 thermal data

Figure 31. PowerSSO-24 PC board



Note: Layout condition of  $R_{th}$  and  $Z_{th}$  measurements (PCB: double layer, thermal vias, FR4 area= 77mm x 86mm, PCB thickness=1.6mm, Cu thickness=70mm (front and back side), copper areas: from minimum pad lay-out to 8cm<sup>2</sup>).

Figure 32.  $R_{thj-amb}$  vs PCB copper area in open box free air condition (one channel ON)

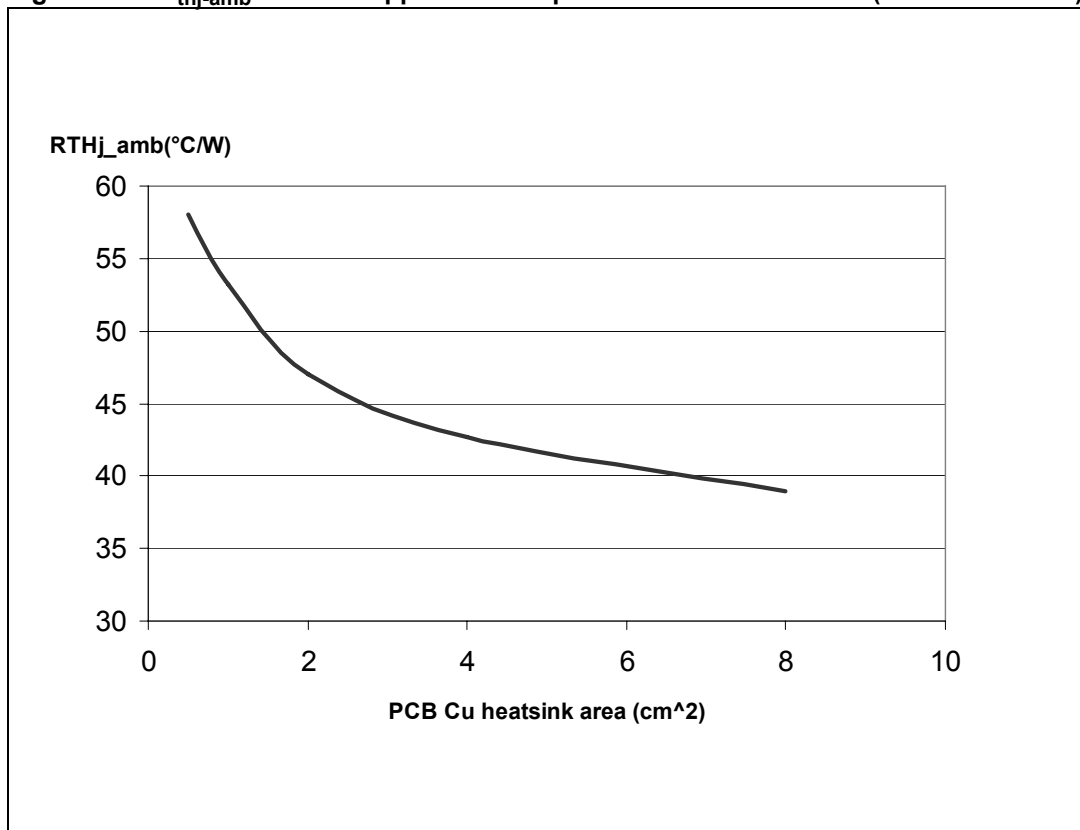


Figure 33. PowerSSO-24 thermal impedance junction ambient single pulse (one channel on)

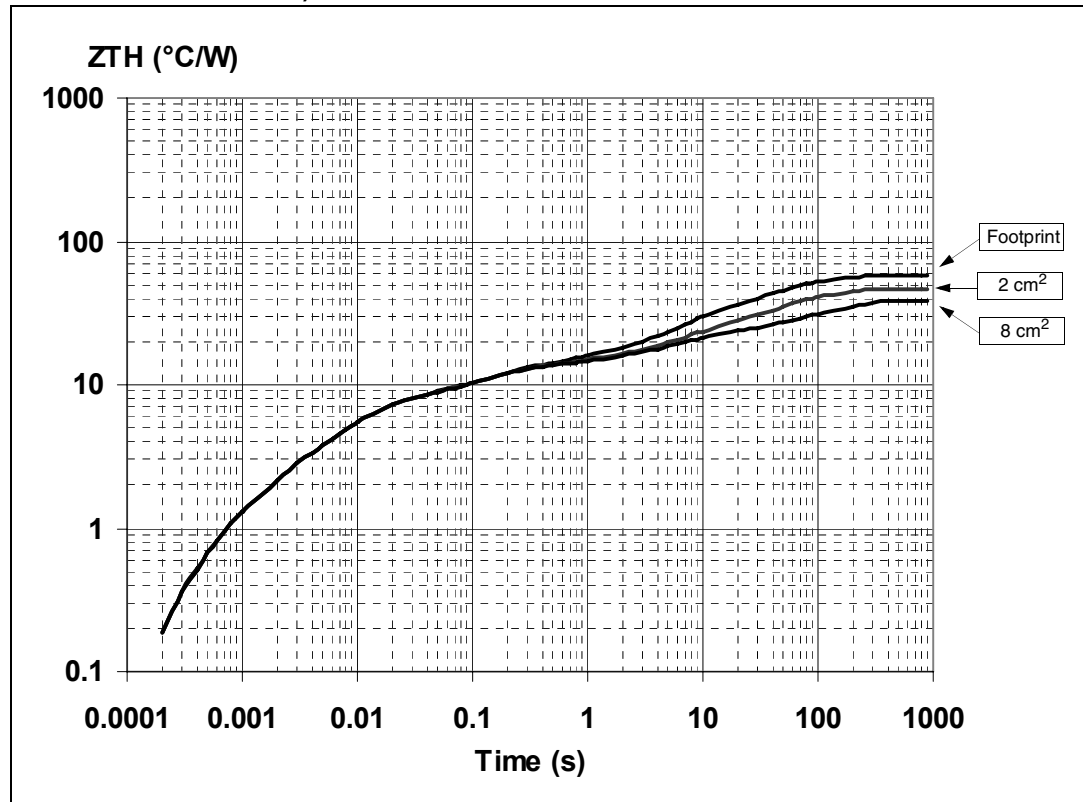
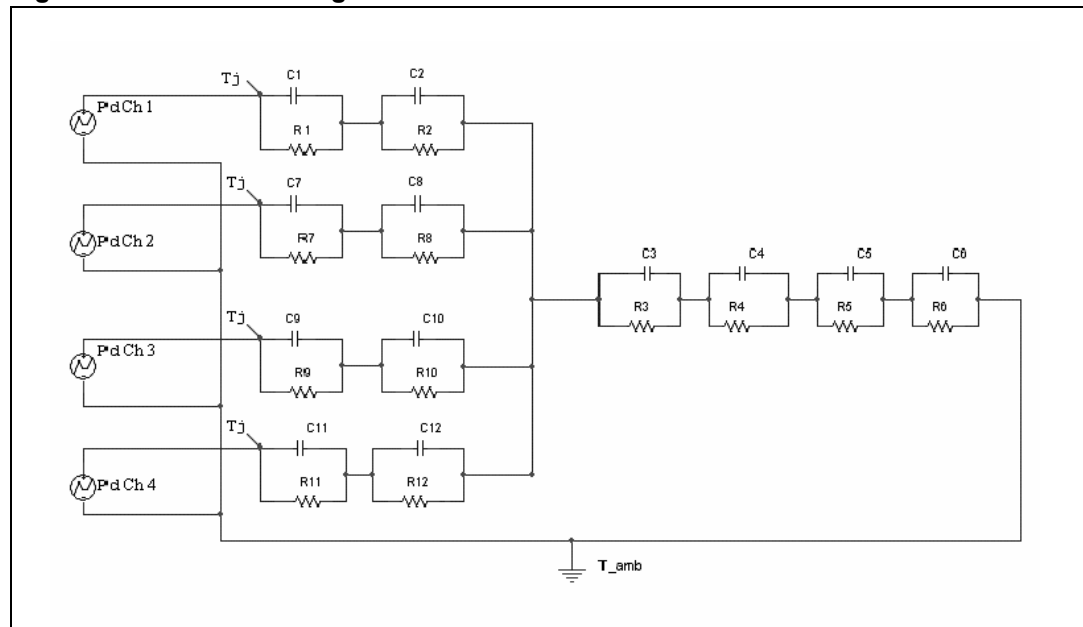


Figure 34. Thermal fitting model of a double channel HSD in PowerSSO-24<sup>(1)</sup>



1. The fitting model is a simplified thermal tool and is valid for transient evolutions where the embedded protections (power limitation or thermal cycling during thermal shutdown) are not triggered

**Equation 1: pulse calculation formula:**

$$Z_{TH\delta} = R_{TH} \cdot \delta + Z_{THtp} (1 - \delta)$$

where  $\delta = t_p/T$

**Table 16. Thermal parameters**

| Area/island (cm <sup>2</sup> ) | Footprint | 2  | 8  |
|--------------------------------|-----------|----|----|
| R1 = R7 = R9 = R11 (°C/W)      | 1.2       |    |    |
| R2 = R8 = R10 = R12 (°C/W)     | 6         |    |    |
| R3 (°C/W)                      | 6         |    |    |
| R4 (°C/W)                      | 7.7       |    |    |
| R5 (°C/W)                      | 9         | 9  | 8  |
| R6 (°C/W)                      | 28        | 17 | 10 |
| C1 = C7 = C9 = C11 (W.s/°C)    | 0.0008    |    |    |
| C2 = C8 = C10 = C12 (W.s/°C)   | 0.0016    |    |    |
| C3 (W.s/°C)                    | 0.025     |    |    |
| C4 (W.s/°C)                    | 0.75      |    |    |
| C5 (W.s/°C)                    | 1         | 4  | 9  |
| C6 (W.s/°C)                    | 2.2       | 5  | 17 |



Table 17. PowerSSO-24™ mechanical data

| Symbol | Millimeters |      |       |
|--------|-------------|------|-------|
|        | Min         | Typ  | Max   |
| A      |             |      | 2.45  |
| A2     | 2.15        |      | 2.35  |
| a1     | 0           |      | 0.1   |
| b      | 0.33        |      | 0.51  |
| c      | 0.23        |      | 0.32  |
| D      | 10.10       |      | 10.50 |
| E      | 7.4         |      | 7.6   |
| e      |             | 0.8  |       |
| e3     |             | 8.8  |       |
| F      |             | 2.3  |       |
| G      |             |      | 0.1   |
| H      | 10.1        |      | 10.5  |
| h      |             |      | 0.4   |
| k      | 0°          |      | 8°    |
| L      | 0.55        |      | 0.85  |
| O      |             | 1.2  |       |
| Q      |             | 0.8  |       |
| S      |             | 2.9  |       |
| T      |             | 3.65 |       |
| U      |             | 1.0  |       |
| N      |             |      | 10°   |
| X      | 4.1         |      | 4.7   |
| Y      | 6.5         |      | 7.1   |

### 5.3 Packing information

Figure 36. PowerSSO-24 tube shipment (no suffix)

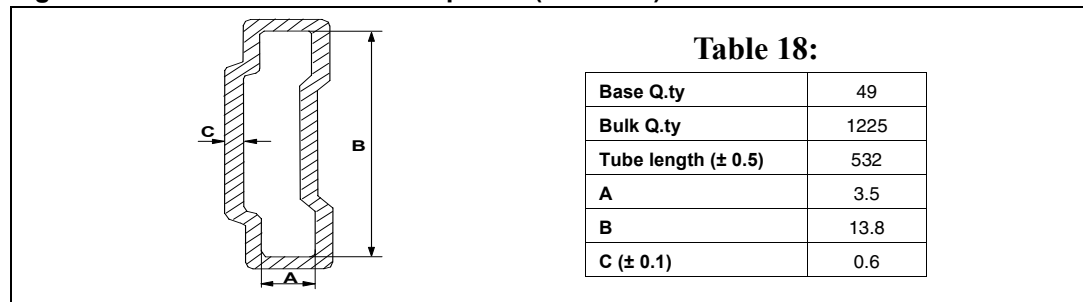
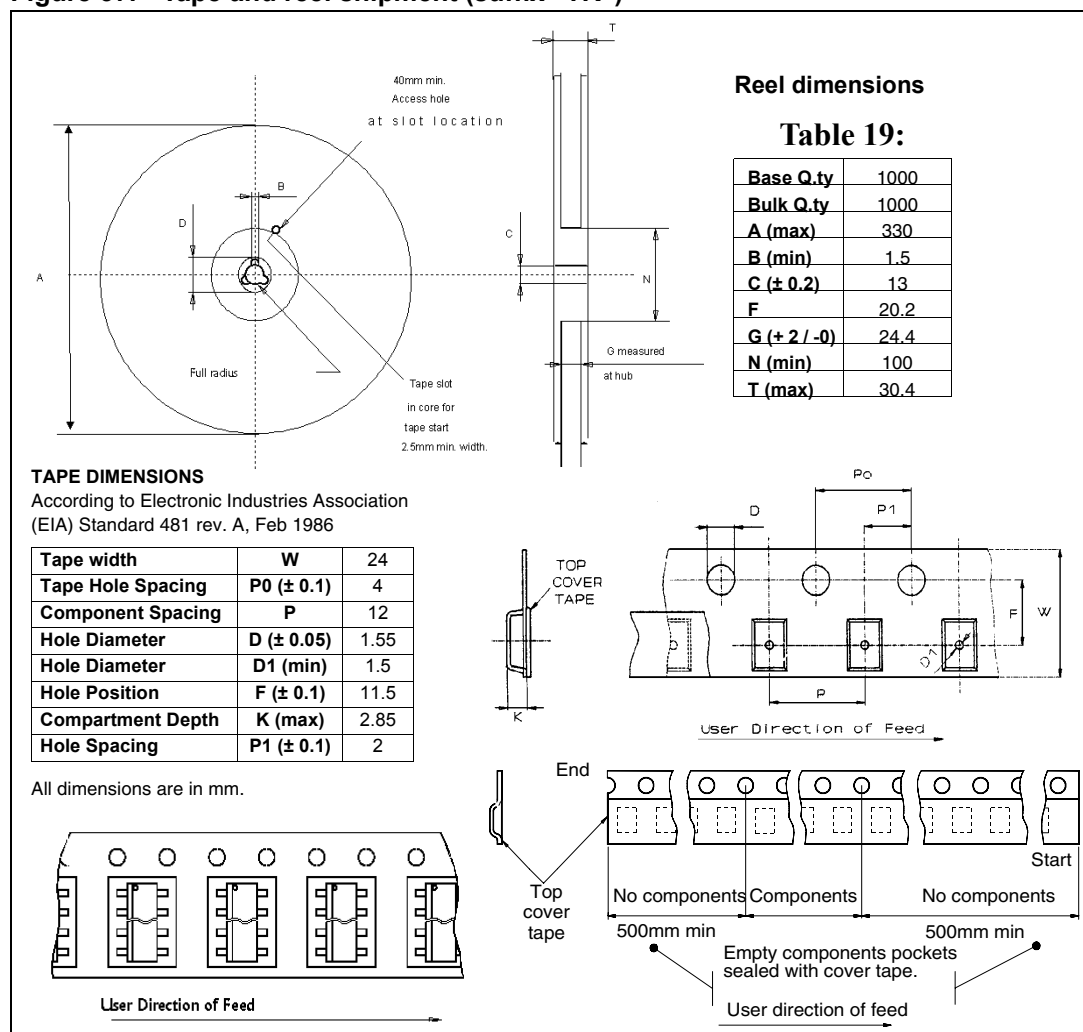


Figure 37. Tape and reel shipment (suffix “TR”)



## 6 Revision history

**Table 20. Document revision history**

| Date        | Revision | Changes                                                                                                                                                                                                                                                                                                                                    |
|-------------|----------|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 8-Jan-2004  | 1        | Initial release.                                                                                                                                                                                                                                                                                                                           |
| 20-Jan-2006 | 2        | Major general update                                                                                                                                                                                                                                                                                                                       |
| 15-Mar-2007 | 3        | Reformatted and restructured.<br>Contents, List of tables and List of figures added.<br><a href="#">Section 3.5: Maximum demagnetization energy (VCC = 13.5V)</a> added.<br><a href="#">Section 5.1: ECOPACK® packages</a> information added.<br>New disclaimer added.                                                                     |
| 01-Jun-2007 | 4        | <a href="#">Table 4: Absolute maximum ratings</a> : EMAX entries updated.<br><a href="#">Table 13: Electrical transient requirements (part 1/3)</a> : Test level values III and IV for test pulse 5b and notes updated<br><a href="#">Figure 34: Thermal fitting model of a double channel HSD in PowerSSO-24<sup>(1)</sup></a> note added |
| 22-Jun-2009 | 5        | <a href="#">Table 17: PowerSSO-24™ mechanical data</a> :<br>– Deleted A (min) value<br>– Changed A (max) value from 2.47 to 2.45<br>– Changed A2 (max) value from 2.40 to 2.35<br>– Changed a1 (max) value from 0.075 to 0.1<br>Added F and k rows                                                                                         |
| 23-Jul-2009 | 6        | Updated <a href="#">Figure 35: PowerSSO-24™ package dimensions</a> .<br>Updated <a href="#">Table 17: PowerSSO-24™ mechanical data</a> :<br>– Deleted G1 row<br>– Added O, Q, S, T and U rows                                                                                                                                              |

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